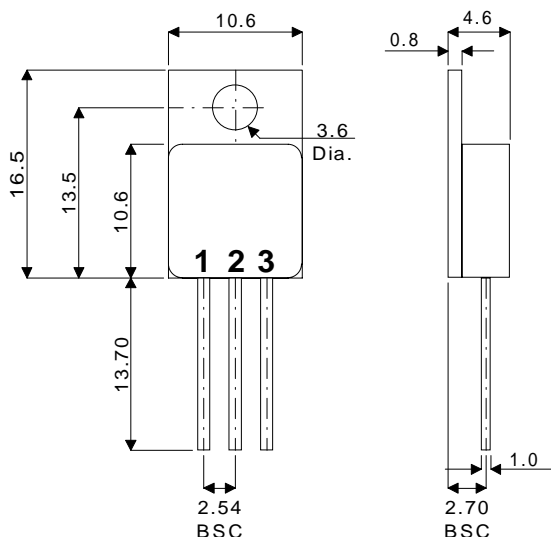


MECHANICAL DATA

Dimensions in mm



TO220 METAL PACKAGE

**DUAL SCHOTTKY
BARRIER DIODE IN
TO220 METAL PACKAGE
FOR HI-REL APPLICATIONS**

FEATURES

- HERMETIC TO220 METAL PACKAGE
- ISOLATED CASE
- SCREENING OPTIONS AVAILABLE
- OUTPUT CURRENT 16A

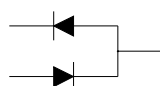
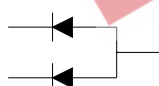
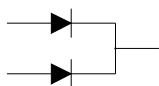
ELECTRICAL CONNECTIONS

Common Cathode Common Anode Series Connection

SB16-100M

SB16-100AM

SB16-100RM



1 = A₁ Anode 1
2 = K Cathode
3 = A₂ Anode 2

1 = K₁ Cathode 1
2 = A Anode
3 = K₂ Cathode 2

1 = K₁ Cathode 1
2 = Centre Tap
3 = A₂ Anode

- LOW V_F
- LOW LEAKAGE

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25°C unless otherwise stated)

		SB16-100M SB16-100AM SB16-100RM
V _{RRM}	Peak Repetitive Reverse Voltage	100V
V _{RSM}	Peak Non-Repetitive Reverse Voltage	100V
V _R	Continuous Reverse Voltage	100V
I _O	Output Current	16A
I _{FSM}	Peak Non-Repetitive Surge Current (50Hz)	245A
T _{STG}	Storage Temperature Range	-55°C to 150°C
T _J	Maximum Operating Junction Temperature	150°C/W

ELECTRICAL CHARACTERISTICS (Per Diode)($T_{CASE} = 25^{\circ}C$ unless otherwise stated)

Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_F Forward Voltage	$I_F = 8A$ $T_J = 150^{\circ}C$			0.8	V
	$I_F = 16A$ $T_J = 25^{\circ}C$			1.0	
I_R Reverse Current	$V_R = V_{RRM}$ $T_J = 150^{\circ}C$			30	mA
	$V_R = V_{RRM}$ $T_J = 25^{\circ}C$			500	μA
C_d Junction Capacitance	$V_R = 5 V$ $f = 1 MHz$		500		pF

Pulse test $t_p=300\mu s$ $\delta \leq 2\%$

Parameter		Unit
$R_{TH(j-a)}$	Maximum Thermal Resistance Junction To Case	both diodes 1.4 per diode 2.3
$R_{TH(j-c)}$	Maximum Thermal Resistance Junction To Case	1.3